

Silicon Diode

GI1402

100V / 8A

DATASHEET

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OEM – General Semiconductor

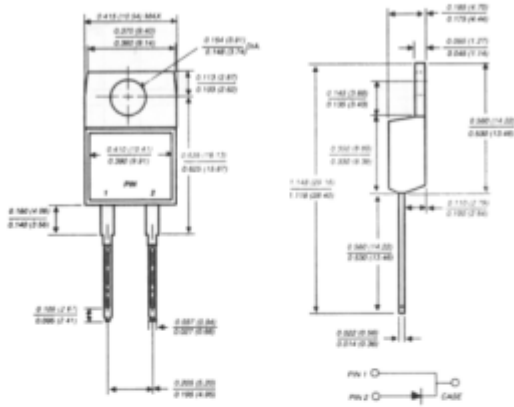
Source: General Semiconductor Databook 1998

GI1401 THRU GI1404

FAST EFFICIENT PLASTIC RECTIFIER

Reverse Voltage - 50 to 200 Volts Forward Current - 8.0 Amperes

TO-220AC



Dimensions in inches and (millimeters)

FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- ◆ Glass passivated chip junction
- ◆ Low power loss
- ◆ Low leakage current
- ◆ High surge capability
- ◆ Superfast recovery time for high efficiency
- ◆ High temperature soldering guaranteed: 250°C, 0.16" (4.06mm) from case for 10 seconds



MECHANICAL DATA

Case: JEDEC TO-220AC molded plastic body over passivated chip

Terminals: Lead solderable per MIL-STD-750, Method 2026

Polarity: As marked

Mounting Position: Any

Weight: 0.064 ounce, 1.81 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	GI1401	GI1402	GI1403	GI1404	UNITS
Maximum recurrent peak reverse voltage	VRRM	50	100	150	200	Volts
Maximum RMS voltage	VRMS	35	70	105	140	Volts
Maximum DC blocking voltage	VDC	50	100	150	200	Volts
Maximum average forward rectified current at T _C =125°C	I _{F(AV)}	8.0				Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) at T _C =125°C	I _{FSM}	125.0				Amps
Maximum instantaneous forward voltage at: I _F =4A, T _J =100°C I _F =8A, T _J =100°C I _F =4A, T _J =25°C I _F =8A, T _J =25°C	V _F	0.800 0.895 0.900 0.975				Volts
Maximum DC reverse current at rated DC blocking voltage T _C =25°C T _C =100°C	I _R	5.0 150.0				µA
Maximum reverse recovery time (NOTE 1)	t _{rr}	35.0				ns
Typical junction capacitance (NOTE 2)	C _J	85.0				pF
Typical thermal resistance (NOTE 3)	R _{θJA}	15.0				°C/W
(NOTE 4)	R _{θJC}	2.2				
Operating and storage temperature range	T _J , T _{STG}	-65 to +150				°C

NOTES:

- (1) Reverse recovery test conditions: I_r=0.5A, I_r=1.0A, I_r=0.25A
- (2) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts
- (3) Thermal resistance from junction to ambient in free air, no heatsink
- (4) Thermal resistance from junction to case mounted on heatsink

RATINGS AND CHARACTERISTIC CURVES G11401 THRU G11404

